



# BTA/BTB16 and T16 Series

**SNUBBERLESS™, LOGIC LEVEL & STANDARD**

**16A TRIACs**

## MAIN FEATURES:

Symbol	Value	Unit
I <sub>T(RMS)</sub>	16	A
V <sub>DRM/V<sub>RRM</sub></sub>	600, 700 and 800	V
I <sub>GT (Q<sub>1</sub>)</sub>	10 to 50	mA

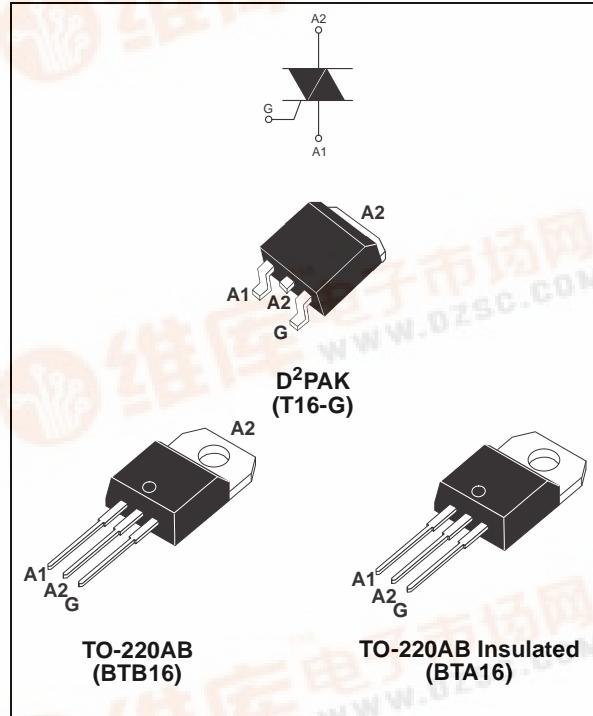
## DESCRIPTION

Available either in through-hole or surface-mount packages, the BTA/BTB16 and T16 triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits... or for phase control operation in light dimmers, motor speed controllers, ...

The snubberless versions (BTA/BTB...W and T16 series) are specially recommended for use on inductive loads, thanks to their high commutation performances. By using an internal ceramic pad, the BTA series provides voltage insulated tab (rated at 2500V RMS) complying with UL standards (File ref.: E81734).

## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Value	Unit
I <sub>T(RMS)</sub>	RMS on-state current (full sine wave)	D2 <sup>2</sup> PAK	T <sub>c</sub> = 100°C	16	A
		TO-220AB	T <sub>c</sub> = 85°C		
		TO-220AB Ins.			
I <sub>TSM</sub>	Non repetitive surge peak on-state current (full cycle, T <sub>j</sub> initial = 25°C)	F = 60 Hz	t = 16.7 ms	168	A
		F = 50 Hz	t = 20 ms	160	
I <sup>2</sup> t	I <sup>2</sup> t Value for fusing	tp = 10 ms		144	A <sup>2</sup> s
dI/dt	Critical rate of rise of on-state current I <sub>G</sub> = 2 x I <sub>GT</sub> , tr ≤ 100 ns	F = 120 Hz	T <sub>j</sub> = 125°C	50	A/μs
V <sub>DSM/V<sub>RSM</sub></sub>	Non repetitive surge peak off-state voltage	tp = 10 ms	T <sub>j</sub> = 25°C	V <sub>DRM/V<sub>RRM</sub></sub> + 100	V
I <sub>GM</sub>	Peak gate current	tp = 20 μs	T <sub>j</sub> = 125°C	4	A
P <sub>G(AV)</sub>	Average gate power dissipation		T <sub>j</sub> = 125°C	1	W
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125	°C



## BTA/BTB16 and T16 Series

ELECTRICAL CHARACTERISTICS ( $T_j = 25^\circ\text{C}$ , unless otherwise specified)

### ■ SNUBBERLESS™ and LOGIC LEVEL (3 Quadrants)

Symbol	Test Conditions	Quadrant		T16	BTA/BTB16			Unit
				T1635	SW	CW	BW	
$I_{GT}$ (1)	$V_D = 12 \text{ V}$ $R_L = 33 \Omega$	I - II - III	MAX.	35	10	35	50	mA
$V_{GT}$		I - II - III	MAX.			1.3		V
$V_{GD}$	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 125^\circ\text{C}$	I - II - III	MIN.			0.2		V
$I_H$ (2)	$I_T = 500 \text{ mA}$		MAX.	35	15	35	50	mA
$I_L$	$I_G = 1.2 I_{GT}$	I - III	MAX.	50	25	50	70	mA
		II		60	30	60	80	
$dV/dt$ (2)	$V_D = 67\% V_{DRM}$ gate open $T_j = 125^\circ\text{C}$		MIN.	500	40	500	1000	V/ $\mu\text{s}$
(dI/dt)c (2)	(dV/dt)c = 0.1 V/ $\mu\text{s}$	$T_j = 125^\circ\text{C}$	MIN.	-	8.5	-	-	A/ms
	(dV/dt)c = 10 V/ $\mu\text{s}$	$T_j = 125^\circ\text{C}$		-	3.0	-	-	
	Without snubber	$T_j = 125^\circ\text{C}$		8.5	-	8.5	14	

### ■ STANDARD (4 Quadrants)

Symbol	Test Conditions	Quadrant		BTA/BTB16		Unit
				C	B	
$I_{GT}$ (1)	$V_D = 12 \text{ V}$ $R_L = 33 \Omega$	I - II - III	MAX.	25	50	mA
		IV		50	100	
$V_{GT}$		ALL	MAX.		1.3	V
$V_{GD}$	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 125^\circ\text{C}$	ALL	MIN.		0.2	V
$I_H$ (2)	$I_T = 500 \text{ mA}$		MAX.	25	50	mA
$I_L$	$I_G = 1.2 I_{GT}$	I - III - IV	MAX.	40	60	mA
		II		80	120	
$dV/dt$ (2)	$V_D = 67\% V_{DRM}$ gate open $T_j = 125^\circ\text{C}$		MIN.	200	400	V/ $\mu\text{s}$
(dI/dt)c(2)	(dI/dt)c = 7 A/ms	$T_j = 125^\circ\text{C}$	MIN.	5	10	V/ $\mu\text{s}$

## STATIC CHARACTERISTICS

Symbol	Test Conditions			Value	Unit	
$V_{TM}$ (2)	$I_{TM} = 22.5 \text{ A}$	$t_p = 380 \mu\text{s}$	$T_j = 25^\circ\text{C}$	MAX.	1.55	V
$V_{to}$ (2)	Threshold voltage		$T_j = 125^\circ\text{C}$	MAX.	0.85	V
$R_d$ (2)	Dynamic resistance		$T_j = 125^\circ\text{C}$	MAX.	25	m $\Omega$
$I_{DRM}$	$V_{DRM} = V_{RRM}$	$T_j = 25^\circ\text{C}$	MAX.	5	$\mu\text{A}$	
		$T_j = 125^\circ\text{C}$		2	mA	

Note 1: minimum  $I_{GT}$  is guaranteed at 5% of  $I_{GT}$  max.

Note 2: for both polarities of A2 referenced to A1

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### THERMAL RESISTANCES

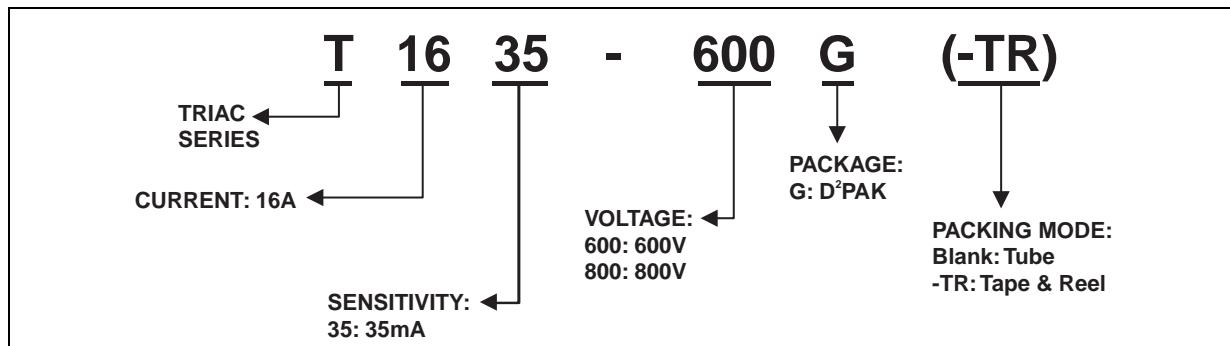
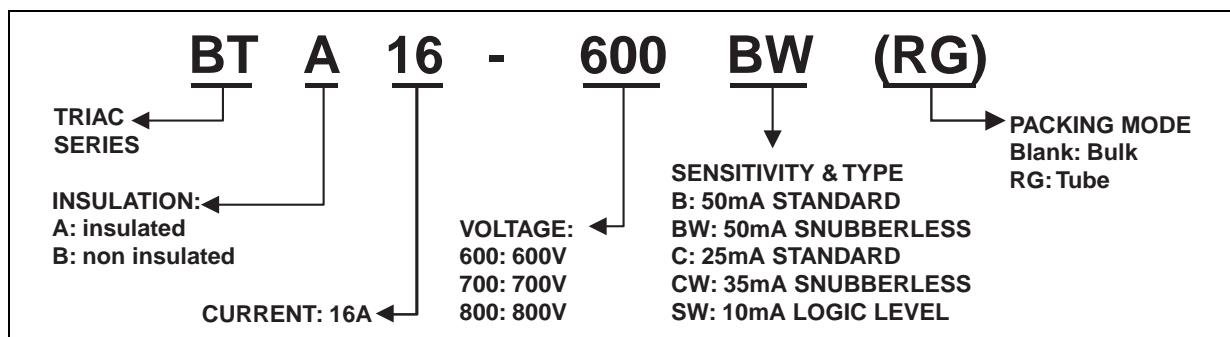
Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (AC)		D <sup>2</sup> PAK TO-220AB	1.2
	TO-220AB Insulated		2.1	
$R_{th(j-a)}$	Junction to ambient	$S = 1 \text{ cm}^2$	D <sup>2</sup> PAK	45
			TO-220AB	60
			TO-220AB Insulated	

S: Copper surface under tab

### PRODUCT SELECTOR

Part Number	Voltage(xxx)			Sensitivity	Type	Package
	600 V	700 V	800 V			
BTA/BTB16-xxxB	X	X	X	50 mA	Standard	TO-220AB
BTA/BTB16-xxxBW	X	X	X	50 mA	Snubberless	TO-220AB
BTA/BTB16-xxxC	X	X	X	25 mA	Standard	TO-220AB
BTA/BTB16-xxxCW	X	X	X	35 mA	Snubberless	TO-220AB
BTA/BTB16-xxxSW	X	X	X	10 mA	Logic level	TO-220AB
T1635-xxxG	X		X	35 mA	Snubberless	D <sup>2</sup> PAK

### ORDERING INFORMATION



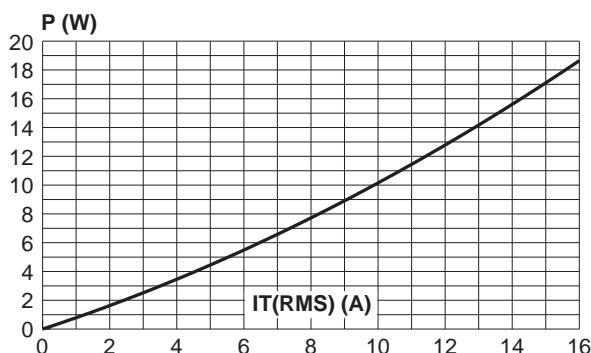
## BTA/BTB16 and T16 Series

### OTHER INFORMATION

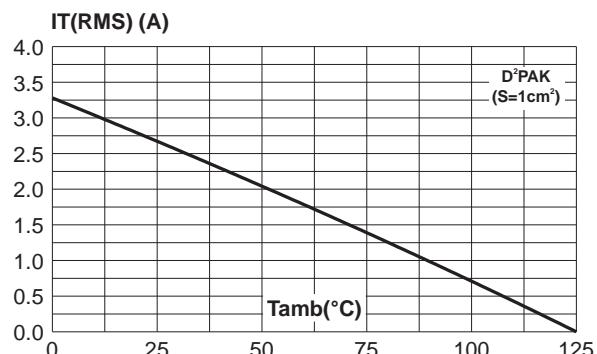
Part Number	Marking	Weight	Base quantity	Packing mode
BTA/BTB16-xxxxz	BTA/BTB16xxxxz	2.3 g	250	Bulk
BTA/BTB16-xxxxzRG	BTA/BTB16-xxxxz	2.3 g	50	Tube
T1635-xxxG	T1635xxxG	1.5 g	50	Tube
T1635-xxxG-TR	T1635xxxG	1.5 g	1000	Tape & reel

Note: xxx = voltage, y = sensitivity, z = type

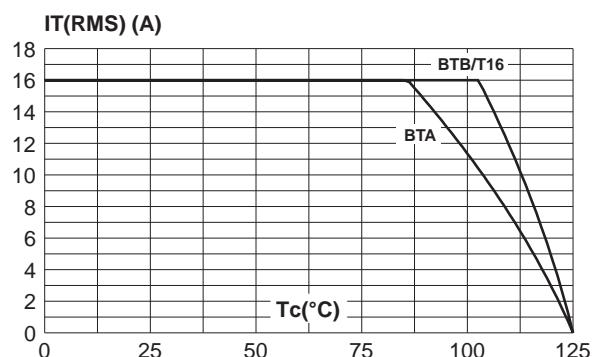
**Fig. 1:** Maximum power dissipation versus RMS on-state current (full cycle).



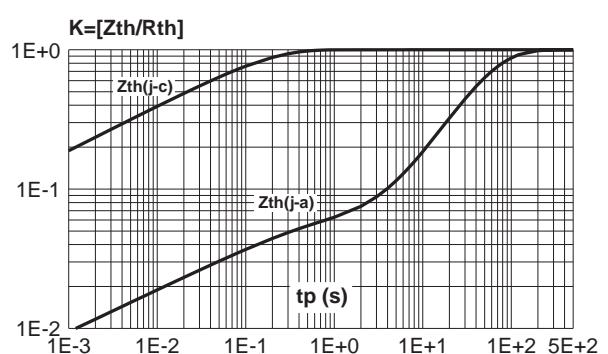
**Fig. 2-2:** D<sup>2</sup>PAK RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35 µm), full cycle.



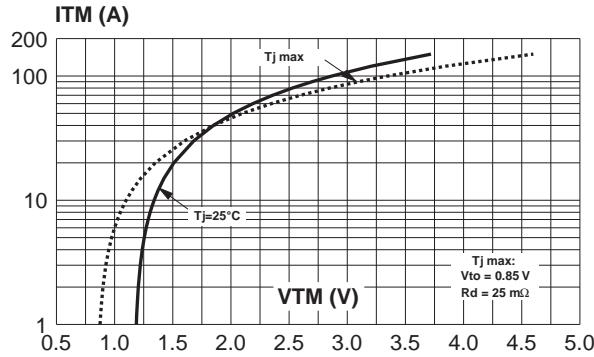
**Fig. 2-1:** RMS on-state current versus case temperature (full cycle).



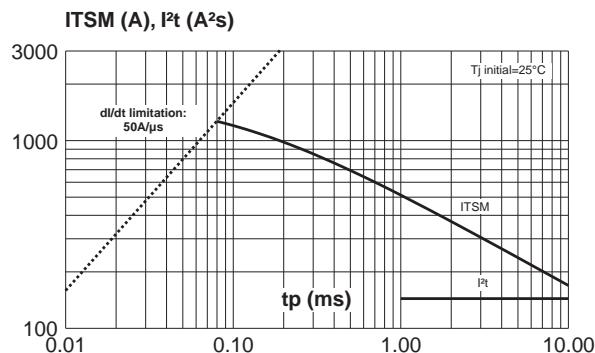
**Fig. 3:** Relative variation of thermal impedance versus pulse duration.



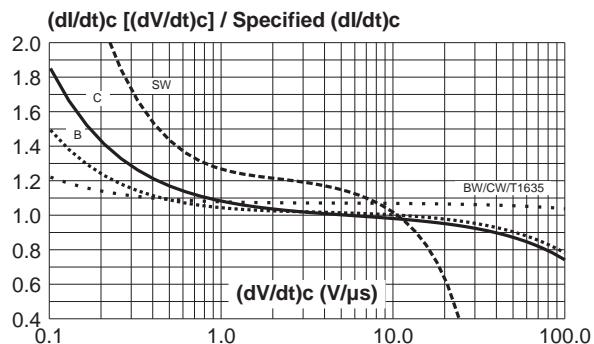
**Fig. 4:** On-state characteristics (maximum values)



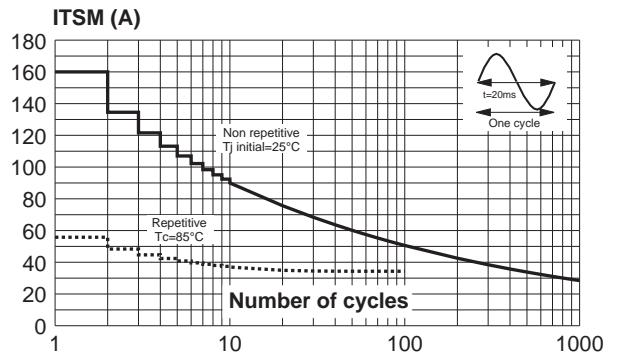
**Fig. 6:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ ms}$ , and corresponding value of  $I^{2t}$ .



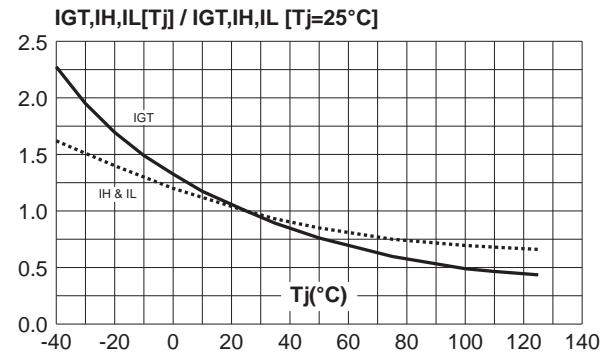
**Fig. 8:** Relative variation of critical rate of decrease of main current versus  $(dV/dt)_c$  (typical values).



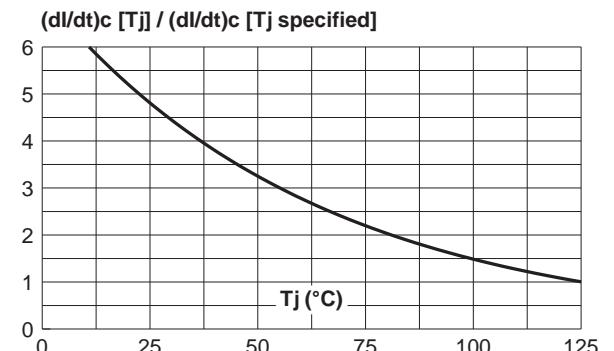
**Fig. 5:** Surge peak on-state current versus number of cycles.



**Fig. 7:** Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values).

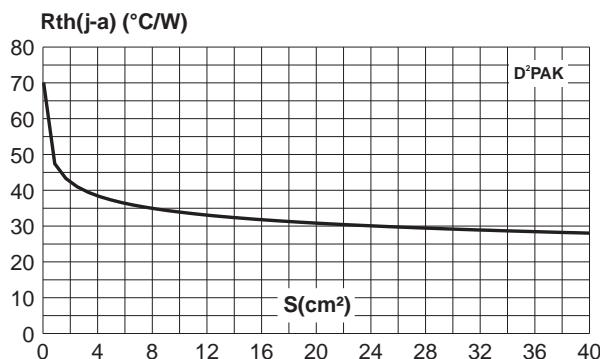


**Fig. 9:** Relative variation of critical rate of decrease of main current versus junction temperature.



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**Fig. 10:**D<sup>2</sup>PAK Thermal resistance junction to ambient versus copper surface under tab (printed circuit board FR4, copper thickness: 35 µm).



## PACKAGE MECHANICAL DATA

TO-220AB (Plastic)

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
I	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	

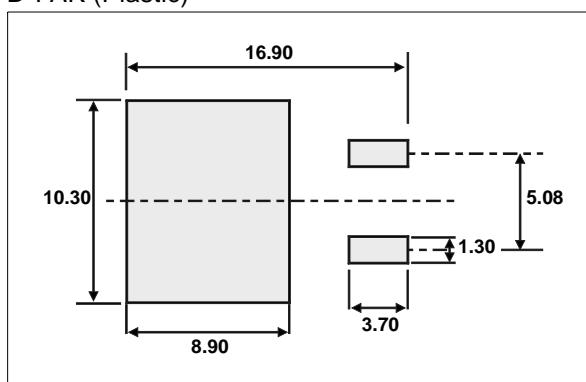
## PACKAGE MECHANICAL DATA

D<sup>2</sup>PAK (Plastic)

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.169		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
B	0.70		0.93	0.027		0.037
B2	1.25	1.40		0.048	0.055	
C	0.45		0.60	0.017		0.024
C2	1.21		1.36	0.047		0.054
D	8.95		9.35	0.352		0.368
E	10.00		10.28	0.393		0.405
G	4.88		5.28	0.192		0.208
L	15.00		15.85	0.590		0.624
L2	1.27		1.40	0.050		0.055
L3	1.40		1.75	0.055		0.069
R		0.40			0.016	
V2	0°		8°	0°		8°

## FOOTPRINT DIMENSIONS (in millimeters)

D<sup>2</sup>PAK (Plastic)



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